

X3-Class HiPerFET™ Power MOSFET

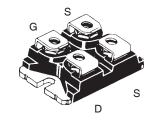
IXFN220N20X3

N-Channel Enhancement Mode Avalanche Rated



$V_{\scriptscriptstyle DSS}$	=	200V
I _{D25}	=	160A
R _{DS(on)}	≤	$6.2 \mathrm{m}\Omega$

miniBLOC, SOT-227 E153432



$$G = Gate$$
 $D = Drain$
 $S = Source$

Symbol	Test Conditions	Maximum Ratings		
V _{DSS} V _{DGR}	$T_J = 25^{\circ}\text{C to } 150^{\circ}$ $T_J = 25^{\circ}\text{C to } 150^{\circ}$		200 200	V
V _{GSS} V _{GSM}	Continuous Transient			V V
I _{D25}	$T_{\rm c} = 25^{\circ}{\rm C}$ $T_{\rm c} = 25^{\circ}{\rm C}$, Pulse Width Limited by $T_{\rm JM}$		160 500	A A
I _A E _{AS}	T _c = 25°C T _c = 25°C		110 2.5	A J
$\overline{\mathbf{P}_{D}}$	T _C = 25°C		390	W
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$		50	V/ns
T _J T _{JM} T _{stg}			-55 +150 150 -55 +150	°C °C °C
V _{ISOL}	50/60 Hz, RMS I _{ISOL} ≤ 1mA	t = 1 minute t = 1 second	2500 3000	V~ V~
\mathbf{M}_{d}	Mounting Torque Terminal Connect		1.5/13 1.3/11.5	Nm/lb.in Nm/lb.in
Weight			30	g

Features

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Isolation Voltage 2500 V~
- High Current Handling Capability
- Avalanche Rated
- Low R_{DS(on)}

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

		cteristic Values Typ. Max.			
BV _{DSS}	$V_{GS} = 0V, I_{D} = 1mA$	200			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 4mA$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 12$	25°C		10 1	μA mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 110A, Note 1$		5.2	6.2	mΩ



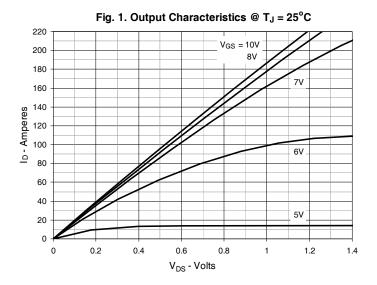
Symbol Test Conditions (T _J = 25°C, Unless Otherwise Specified)		Characteristic Values		
		Min.	Тур.	Max
g _{fs}	$V_{DS} = 10V, I_{D} = 60A, \text{ Note 1}$	70	120	S
R_{Gi}	Gate Input Resistance		1.6	Ω
C _{iss}			13.6	nF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		2.2	nF
C _{rss}			9.0	pF
	Effective Output Capacitance			
$\mathbf{C}_{o(er)}$	Energy related $\int V_{GS} = 0V$		1000	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		3250	pF
t _{d(on)}	Resistive Switching Times		37	ns
t,	_		27	ns
t _{d(off)}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 85A$		155	ns
t_f $R_g = 5\Omega \text{ (External)}$	H _G = 552 (External)		17	ns
Q _{g(on)}			204	nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 85A$		65	nC
\mathbf{Q}_{gd}			47	nC
R _{thJC}				0.32 °C/W
R _{thCS}			0.05	°C/W

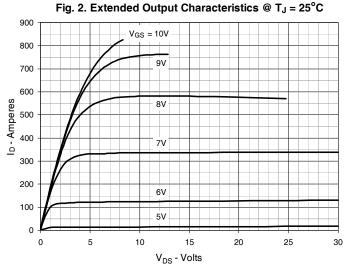
Source-Drain Diode

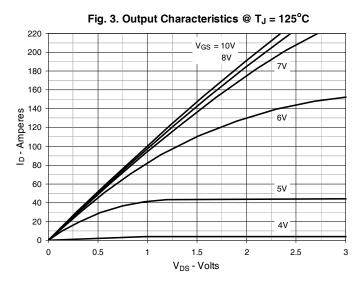
Symbol	Test Conditions	Characteristic Values			
$T_{\rm J} = 25^{\circ}$ C,	Unless Otherwise Specified)	Min.	Тур.	Max.	
I _s	$V_{GS} = 0V$			220	Α
I _{SM}	Repetitive, Pulse Width Limited by $T_{_{JM}}$			880	Α
V _{SD}	$I_F = 100A, V_{GS} = 0V, Note 1$			1.4	V
t _{rr}	I ₌ = 110A, -di/dt = 100A/μs		128		ns
Q _{RM}	1		580		пC
I _{RM}	$V_R = 100V$, $V_{GS} = 0V$		9		Α

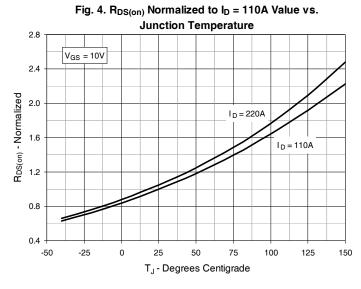
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

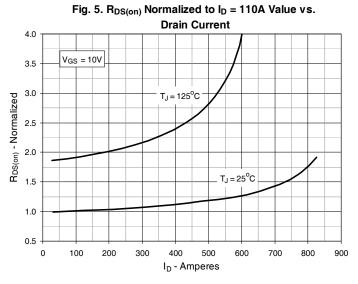


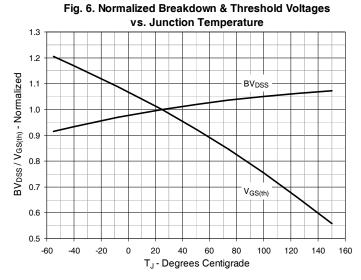








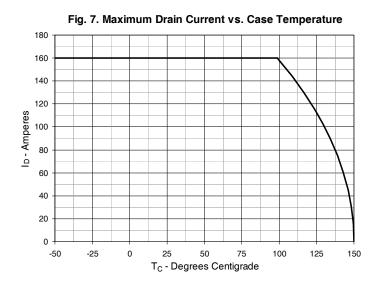


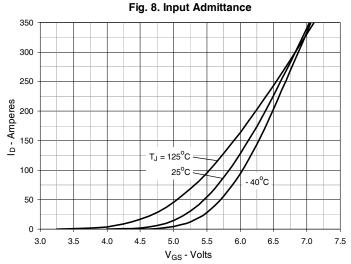


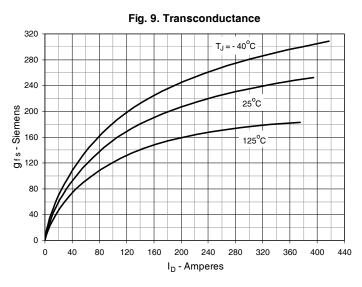
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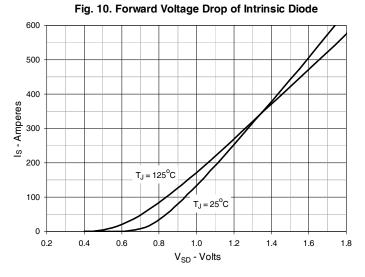
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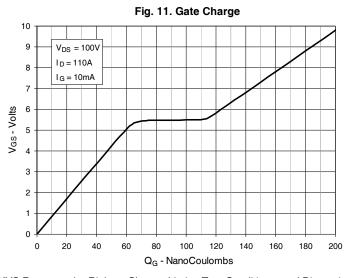


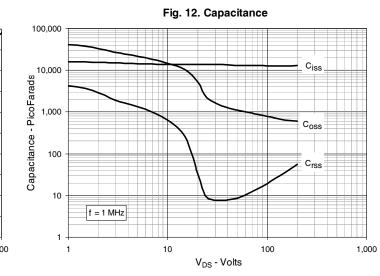






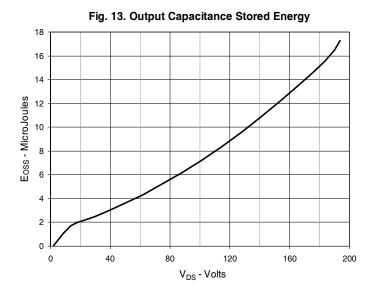






 $\ensuremath{\mathsf{IXYS}}$ Reserves the Right to Change Limits, Test Conditions, and Dimensions.







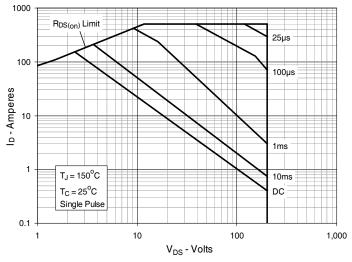
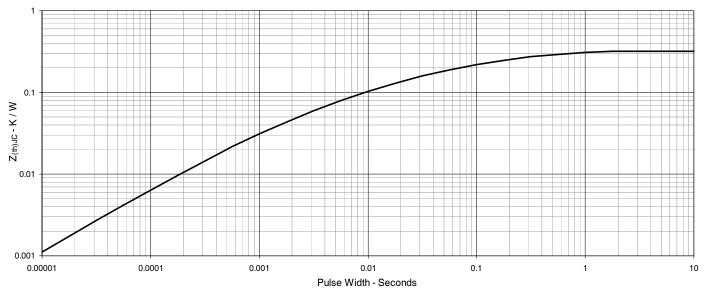
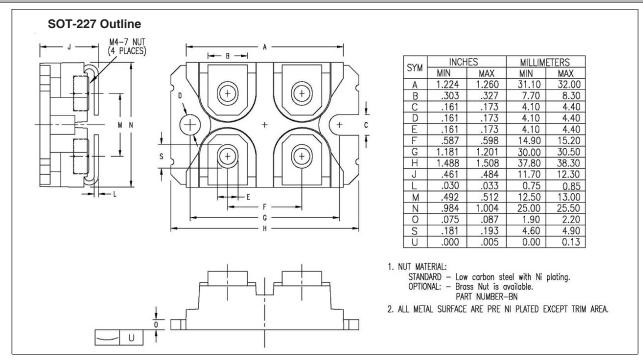


Fig. 15. Maximum Transient Thermal Impedance















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